

Product Summary

| BV _{DSS} | Rds(on) | I _D T _A = +25°C |
|-------------------|-------------------------------|--|
| 50V | 1.6Ω @ V _{GS} = 10V | 500mA |
| 500 | 2.5Ω @ V _{GS} = 4.5V | 200mA |

Features and Benefits

- N-Channel MOSFET
- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 - https://www.diodes.com/quality/product-definitions/
- An automotive-compliant part is available under separate datasheet (DMN53D0LQ)

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.



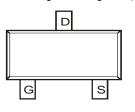




Top View

Mechanical Data

- Package: SOT23 •
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead-Free Plating). Solderable per MIL-STD-202, Method 208 (03)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)





Top View

Equivalent Circuit

Ordering Information (Note 4)

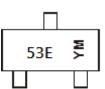
| Part Number | Backage | Packing | | | |
|-------------|---------|---------|-------------|--|--|
| | Package | Qty. | Carrier | | |
| DMN53D0L-7 | SOT23 | 3000 | Tape & Reel | | |
| DMN53D0L-13 | SOT23 | 10000 | Tape & Reel | | |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



53E = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} or \underline{Y} = Year (ex: L = 2024) M = Month (ex: 9 = September)

Date Code Key

Notes:

| | -) | | | | | | | | | | | |
|-------|------|-----|------|------|------|------|------|------|------|------|------|------|
| Year | 2014 | - | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 | 2032 | 2033 |
| Code | В | - | L | М | Ν | Р | R | S | Т | U | V | W |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------|--------|-------|------|
| Drain-Source Voltage | VDSS | 50 | V |
| Gate-Source Voltage | Vgss | ±20 | V |
| Drain Current (Note 5) | lo | 500 | mA |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------------|------|
| Total Power Dissipation (Note 6) | PD | 370 | mW |
| Thermal Resistance, Junction to Ambient (Note 6) | Reja | 344 | °C/W |
| Total Power Dissipation (Note 5) | PD | 540 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{0JA} | 236 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

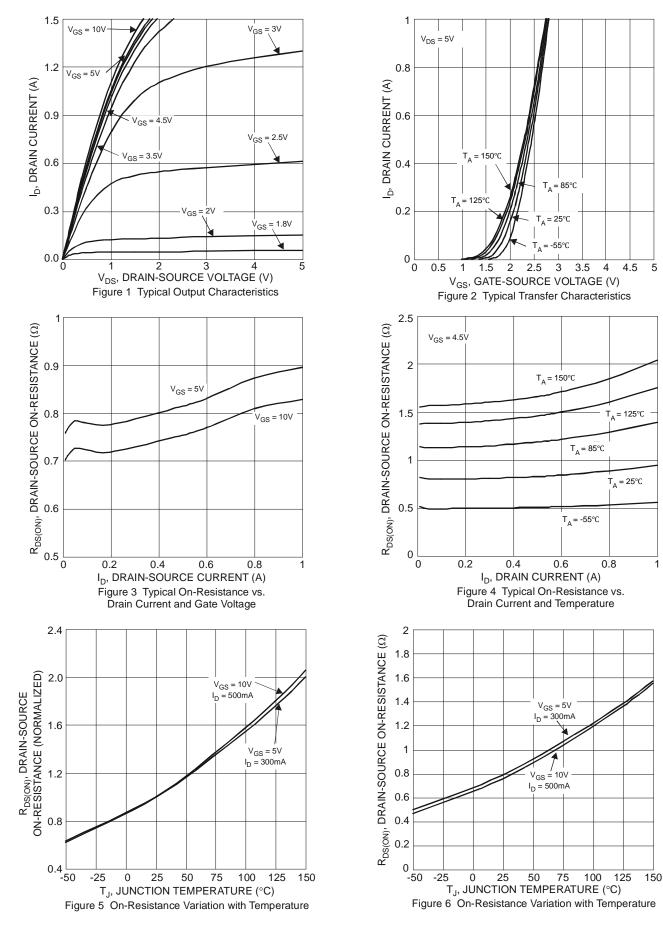
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Мах | Unit | Test Condition | |
|------------------------------------|---------------------|-----|-------|------------|------|---|--|
| OFF CHARACTERISTICS (Note 7) | | | - 71- | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 50 | | | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | | 1.0 | μA | $V_{DS} = 50V, V_{GS} = 0V$ | |
| Gate-Body Leakage | lgss | | | 10 | μA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | 0.8 | | 1.5 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | Rds(on) | — | | 1.6 2.5 | Ω | $V_{GS} = 10V, I_D = 500mA$ $V_{GS} = 4.5V, I_D = 200mA$ | |
| | | | | 4.5 | | $V_{GS} = 2.5V, I_D = 100mA$ | |
| Source-Drain Diode Forward Voltage | Vsd | | | 1.4 | V | Vgs = 0V, Is = 500mA | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | Ciss | | 46 | | pF | V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz | |
| Output Capacitance | Coss | | 5.3 | | pF | | |
| Reverse Transfer Capacitance | Crss | | 4.0 | | pF | | |
| Total Gate Charge | Qg | | 0.6 | | nC | | |
| Gate-Source Charge | Qgs | _ | 0.2 | | nC | $V_{GS} = 4.5V, V_{DS} = 10V$ ID = 250mA | |
| Gate-Drain Charge | Q _{gd} | | 0.1 | | nC | | |
| Turn-On Delay Time | t _{D(on)} | | 2.7 | | ns | | |
| Turn-On Rise Time | tr | | 2.5 | | ns | $V_{DD} = 30V, V_{GS} = 10V$ | |
| Turn-Off Delay Time | tD(off) | | 19 | | ns | $R_G = 25\Omega$, $I_D = 200mA$ | |
| Turn-Off Fall Time | t _f | | 11 | | ns | | |

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



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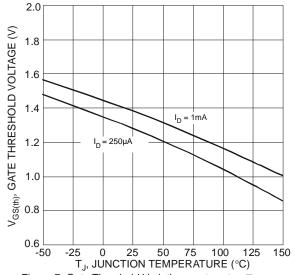
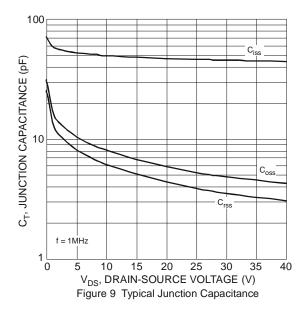
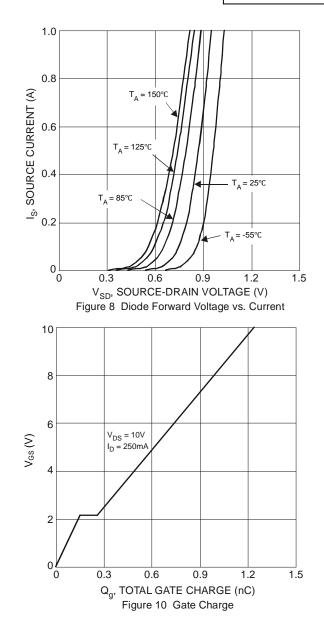


Figure 7 Gate Threshold Variation vs. Junction Temperature

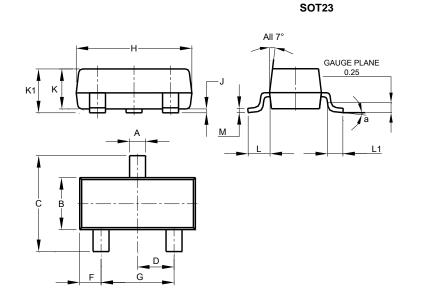






Package Outline Dimensions

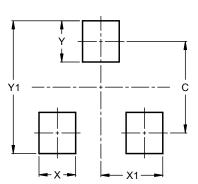
Please see http://www.diodes.com/package-outlines.html for the latest version.



| | SOT23 | | | | | | | |
|-----|----------------------|-------|-------|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | |
| Α | 0.37 | 0.51 | 0.40 | | | | | |
| В | 1.20 | 1.40 | 1.30 | | | | | |
| С | 2.30 | 2.50 | 2.40 | | | | | |
| D | 0.89 | 1.03 | 0.915 | | | | | |
| F | 0.45 | 0.60 | 0.535 | | | | | |
| G | 1.78 | 2.05 | 1.83 | | | | | |
| н | 2.80 | 3.00 | 2.90 | | | | | |
| J | 0.013 | 0.10 | 0.05 | | | | | |
| ĸ | 0.890 | 1.00 | 0.975 | | | | | |
| K1 | 0.903 | 1.10 | 1.025 | | | | | |
| L | 0.45 | 0.61 | 0.55 | | | | | |
| L1 | 0.25 | 0.55 | 0.40 | | | | | |
| М | 0.085 | 0.150 | 0.110 | | | | | |
| а | 0° | 8° | | | | | | |
| All | All Dimensions in mm | | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.0 |
| Х | 0.8 |
| X1 | 1.35 |
| Y | 0.9 |
| Y1 | 2.9 |



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